



DESCRIPTION

The AL4G32 Quadruple 2-input positive-OR gate is designed for 1.65V to 5.5V V_{CC} operation.

The AL4G32 device performs the Boolean function $Y=A + B$ or $Y=\overline{\overline{A} \times \overline{B}}$ in positive logic. The device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The AL4G32 is operate over an ambient temperature range of -40°C to +125°C.

The AL4G32 is available in SOP14 and TSSOP14 Packages.

FEATURES

- Operating Voltage Range: 1.65V to 5.5V
- Low Power Consumption: 1µA (Max).
- Operating Temperature Range: -40°C to +125°C
- Inputs Accept Voltage to 5.5V
- High Output Drive: ±24mA at V_{CC} = 3.0V
- Available in SOP14 and TSSOP14 Packages

APPLICATION

- Combine Active-Low Enable Signals
- User Fewer Inputs to Monitor Error Signal
- AV Receiver
- Blu-ray Player and Home Theater
- Digital Picture Frame (DPF)
- High-Speed Data Acquisition and Generation
- Personal Navigation Device (GPS)
- Portable Media Player

ORDERING INFORMATION

Package Type	Part Number	
SOP14 SPQ: 4,000pcs/Reel	M14	AL4G32M14R
		AL4G32M14VR
TSSOP14 SPQ:4,000pcs/Reel	TMX14	AL4G32TMX14R
		AL4G32TMX14VR
Note	V: Halogen free Package R: Tape & Reel	
AiT provides all RoHS products		

LOGIC SYMBOL



FUNCTION TABLE

Inputs		Output
A	B	Y
H	H	H
L	H	H
H	L	H
L	L	L

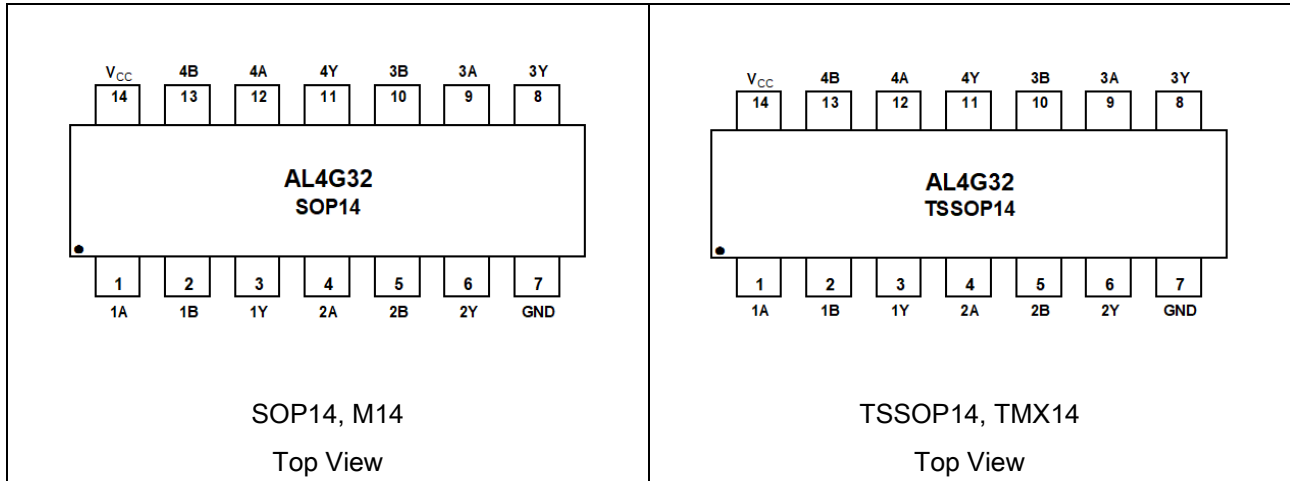
Y=A+B

H=High Voltage Level

L=Low Voltage Level



PIN DESCRIPTION



PIN#		Symbol	I/O	Function
SOP14	TSSOP14			
1	1	1A	I	Channel 1 Logic Input
2	2	1B	I	Channel 1 Logic Input
3	3	1Y	O	Logic Level Output 1
4	4	2A	I	Channel 2 Logic Input
5	5	2B	I	Channel 2 Logic Input
6	6	2Y	O	Logic Level Output 2
7	7	GND	-	Ground
8	8	3Y	O	Logic Level Output 3
9	9	3A	I	Channel 3 Logic Input
10	10	3B	I	Channel 3 Logic Input
11	11	4Y	O	Logic Level Output 4
12	12	4A	I	Channel 4 Logic Input
13	13	4B	I	Channel 4 Logic Input
14	14	V _{CC}	-	Power Supply

I=Input, O=Output, P=Power

**ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range (unless otherwise noted)

V _{CC} , Supply Voltage Range		-0.5V ~ + 6.5V
V _I , Input Voltage Range ⁽²⁾		-0.5V ~ + 6.5V
V _O , Voltage Range to any output in the high-impedance or power -off state ⁽¹⁾		-0.5V ~ + 6.5V
V _O , Voltage Range to any output in the high or low state ⁽¹⁾⁽²⁾		-0.5V ~ V _{CC} +0.5V
I _{IK} , Input Clamp Current	V _I <0	-50mA
I _{OK} , Output Clamp Current	V _O <0	-50mA
I _O , Continuous Output Current		±50mA
I _O , Continuous Current through V _{CC} or GND		±100mA
R _{θJA} , Junction-to-Ambient Thermal Resistance	SOP14	122.2°C/W
	TSSOP14	141.2°C/W
T _J , Junction Temperature		-65°C ~ +150°C
T _{STG} , Storage Temperature		-65°C ~ +150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

- (1) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
(2) The value of V_{CC} is provided in the Recommended Operating Conditions table.

ESD RATINGS

Parameter	Symbol	Min	Unit
Human-Body Model (HBM)	V _(ESD) Electrostatic Discharge	±8000	V
Machine Model (MM)		±500	

**RECOMMENDED OPERATING CONDITIONS**

TA=25°C, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Max	Unit
Supply Voltage	V _{CC}	Operating	1.65	5.5	
		Data Retention only	1.5	5.5	
High-Level Input Voltage	V _{IH}	V _{CC} = 1.65V ~ 1.95V	0.65x V _{CC}	-	V
		V _{CC} = 2.3V ~ 2.7V	1.7	-	
		V _{CC} = 3V ~ 3.6V	2.2	-	
		V _{CC} = 4.5V ~ 5.5V	0.70x V _{CC}	-	
Low-Level Input Voltage	V _{IL}	V _{CC} = 1.65V ~ 1.95V	-	0.15x V _{CC}	V
		V _{CC} = 2.3V ~ 2.7V	-	0.3	
		V _{CC} = 3V ~ 3.6V	-	0.4	
		V _{CC} = 4.5V ~ 5.5V	-	0.15x V _{CC}	
Input Voltage	V _I	-	0	5.5	V
Output Voltage	V _O	-	0	V _{CC}	V
Input Transition Rise or Fall	t _r , t _f	V _{CC} = 1.8V±0.15V, 2.5V±0.2V	-	20	ns/V
		V _{CC} = 3.3V ± 0.3V	-	10	
		V _{CC} = 5V ± 0.5V	-	5	
Operating Temperature	T _A	-	-40	+125	°C

*All unused inputs of the device must be held at VCC or GND to ensure proper device operation.



ELECTRICAL CHARACTERISTICS

TA=25°C, unless otherwise noted.

DC CHARACTERISTICS

Parameter		Conditions	Min	Typ.	Max	Unit
V _{OH}		I _{OH} = -100 μA, V _{CC} = 1.65V ~ 5.5V	V _{CC} ~0.1	-	-	V
		I _{OH} = -4mA, V _{CC} = 1.65V	1.2	-	-	
		I _{OH} = -8mA, V _{CC} = 2.3V	1.9	-	-	
		I _{OH} = -16mA, V _{CC} = 3V	2.4	-	-	
		I _{OH} = -24mA, V _{CC} = 3V	2.3	-	-	
		I _{OH} = -32mA, V _{CC} = 4.5V	3.8	-	-	
V _{OL}		I _{OL} = -100 μA, V _{CC} = 1.65~5.5V	-	-	0.1	V
		I _{OL} = 4mA, V _{CC} = 1.65V	-	-	0.45	
		I _{OL} = 8mA, V _{CC} = 2.3V	-	-	0.3	
		I _{OL} = 16mA, V _{CC} = 3V	-	-	0.4	
		I _{OL} = 24mA, V _{CC} = 3V	-	-	0.55	
		I _{OL} = 32mA, V _{CC} = 4.5V	-	-	0.55	
I _I	A or B Inputs	V _I = 5.5V or GND, V _{CC} = 0V~5.5V	+25°C	±0.1	±1	μA
			-40°C ~ +125°C	-	±5	
I _{off}		V _I or V _O = 5.5V, V _{CC} = 0	+25°C	-	±0.1	μA
			-40°C ~ +125°C	-	±10	
I _{CC}		V _I = 5.5V or GND, I _O = 0, V _{CC} = 1.65V~5.5V	+25°C	-	0.1	μA
			-40°C ~ +125°C	-	10	
ΔI _{CC}		One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND, V _{CC} = 3V~5.5V	-40°C ~ +125°C	-	-	500 μA

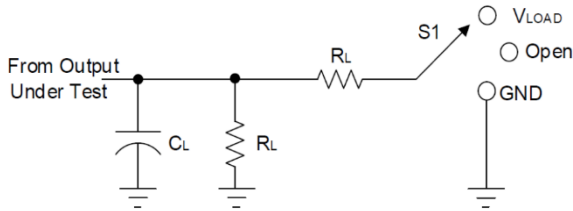
AC CHARACTERISTICS

Parameter	Symbol	Conditions			Typ.	Unit
Input Capacitance	C _i	V _{CC} = 3.3V	V _I = V _{CC} or GND	+25°C	4	ns
Propagation Delay	t _{pd}	V _{CC} = 1.8V±0.15V	C _L = 30pF, R _L = 1KΩ	-40°C ~ +125°C	8	ns
		V _{CC} = 2.5V±0.2V	C _L = 30pF, R _L = 500Ω	-40°C ~ +125°C	3.7	
		V _{CC} = 3.3V±0.3V	C _L = 50pF, R _L = 500Ω	-40°C ~ +125°C	2.5	
		V _{CC} = 5V±0.5V	C _L = 50pF, R _L = 500Ω	-40°C ~ +125°C	2.7	
Power Dissipation Capacitance	C _{pd}	V _{CC} = 1.8V±0.15V	f = 10MHz	+25°C	20	pF
		V _{CC} = 2.5V±0.2V		+25°C	21	
		V _{CC} = 3.3V±0.3V		+25°C	22	
		V _{CC} = 5V±0.5V		+25°C	25	

All unused inputs of the device must be held at VCC or GND to ensure proper device operation.



PARAMETER MEASUREMENT INFORMATION



TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PIZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND

V_{CC}	Inputs		V_M	V_{LOAD}	C_L		R_L		V_{Δ}
	V_I	tr/tf							
$1.8V \pm 0.15V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	30pF	1M Ω	1k Ω	0.15V
$2.5V \pm 0.2V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	30pF	1M Ω	500 Ω	0.15V
$3.3V \pm 0.3V$	3V	$\leq 2.5ns$	1.5V	6V	15pF	30pF	1M Ω	500 Ω	0.3V
$5V \pm 0.5V$	V_{CC}	$\leq 2.5ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	30pF	1M Ω	500 Ω	0.3V

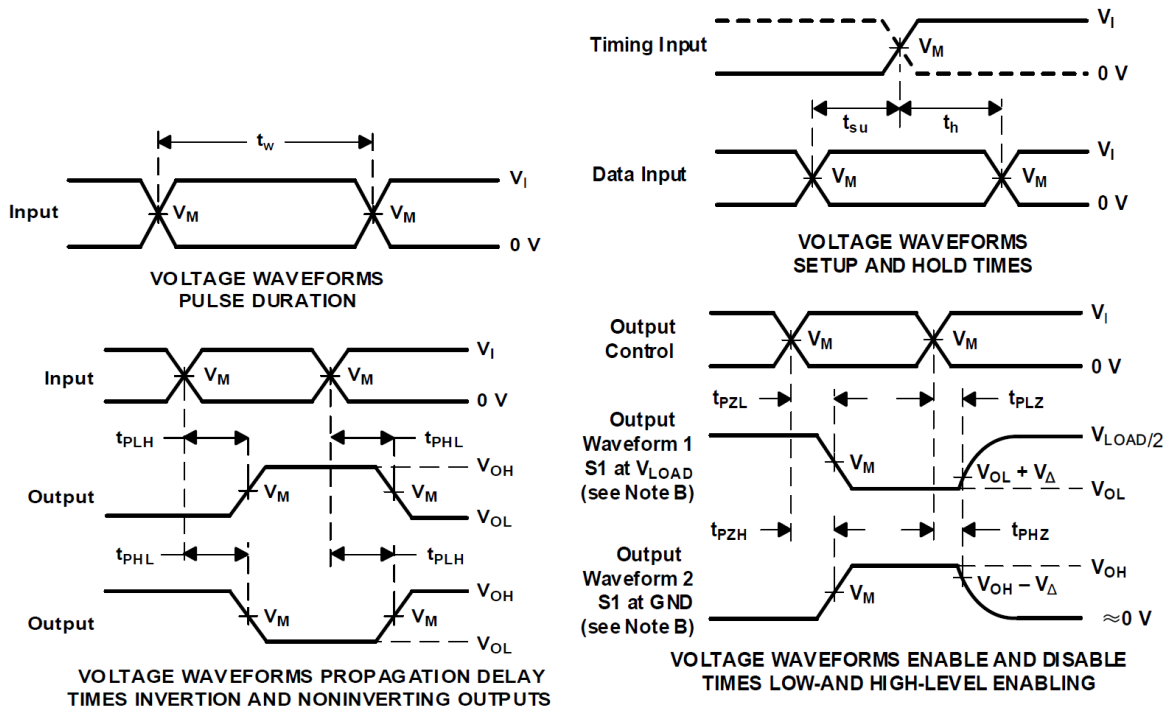


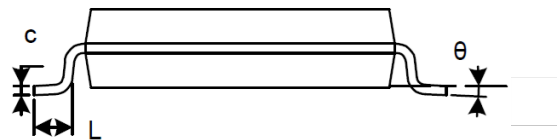
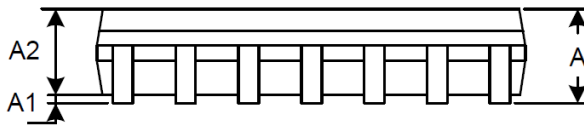
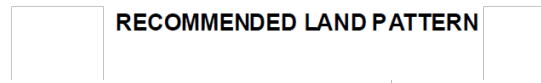
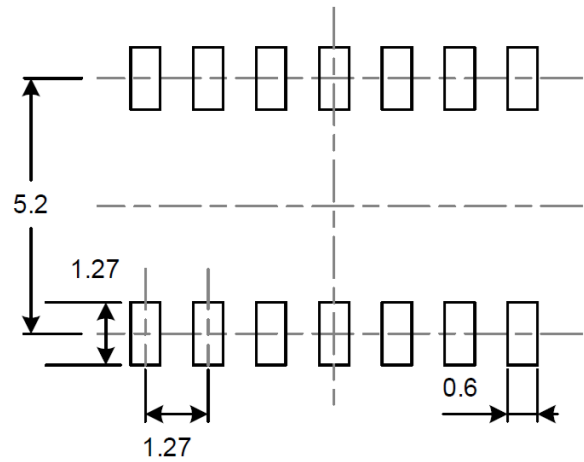
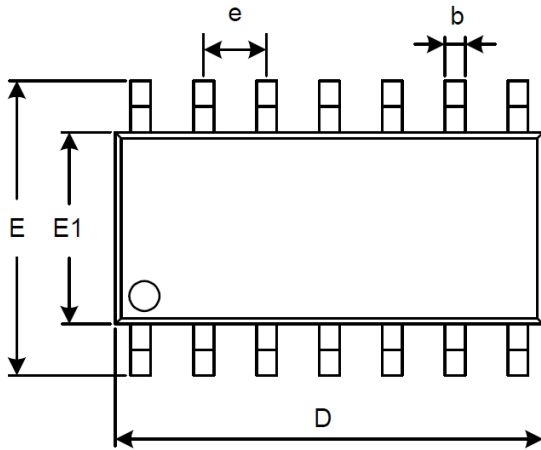
Fig 1. Load Circuit and Voltage Waveforms

- (A) C_L includes probe and jig capacitance.
- (B) Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- (C) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_o = 50 \Omega$.
- (D) The outputs are measured one at a time, with one transition per measurement.
- (E) All parameters and waveforms are not applicable to all devices.



PACKAGE INFORMATION

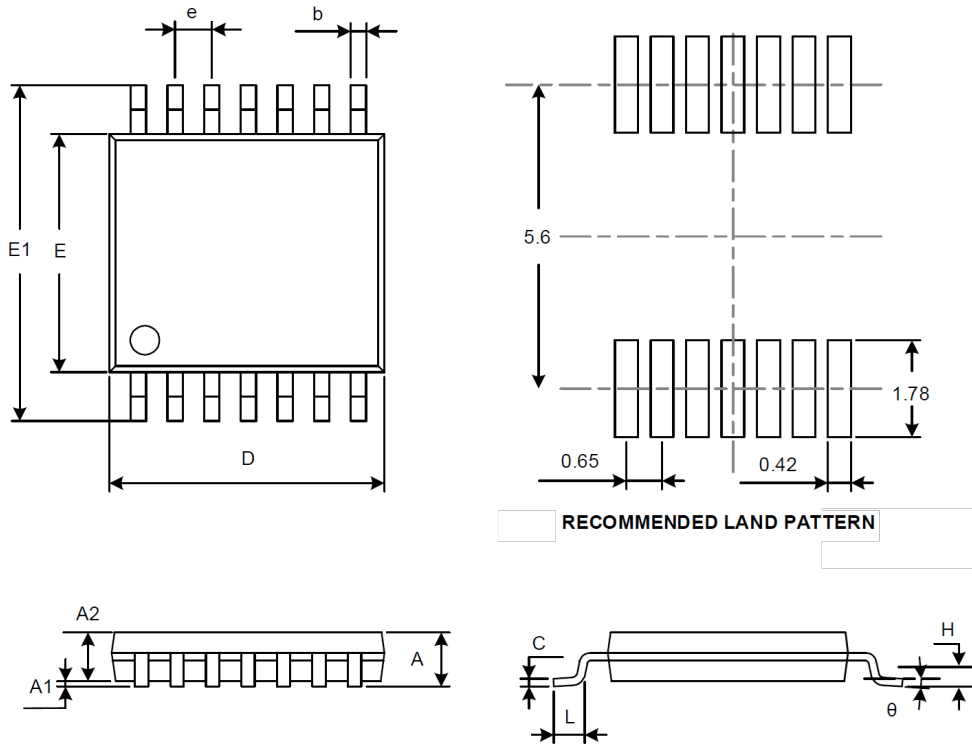
Dimension in SOP14 (Unit: mm)



Symbol	Millimeters	
	Min	Max
A	1.350	1.750
A1	0.100	0.250
A2	1.350	1.550
b	0.310	0.510
c	0.100	0.250
D	8.450	8.850
e	1.270 BSC	
E	5.800	6.200
E1	3.800	4.000
L	0.400	1.270
θ	0°	8°



Dimension in TSSOP14 (Unit: mm)



Symbol	Millimeters	
	Min	Max
A	-	1.200
A1	0.500	0.150
A2	0.800	1.050
b	0.190	0.300
c	0.090	0.200
D	4.860	5.100
E	4.300	4.500
E1	6.250	6.550
e	0.650 BSC	
L	0.500	0.700
H	0.25 TYP	
θ	1°	7°



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